

74HCT32

QUADRUPLE 2-INPUT OR GATES

Description

The 74HCT32 provides provides four independent 2-input OR gates with standard push-pull outputs. The device is designed for operation with a power supply range of 4.5V to 5.5V.

The gates perform the Boolean function:

$$Y = A + B$$
 or $Y = \overline{\overline{A} \bullet \overline{B}}$

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Pin Compatible with Low Power Schottky (LSTTL)
- Inputs Are TTL Voltage Level Compatible
- Sinks or Sources 4mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



SO-14 / TSSOP-14

Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	ЗA	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	V _{CC}	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
Α	A B	
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range (Note 5)	-0.5 to +7.0	V
I _{IK}	Input Clamp Current $V_{I} < -0.5V$ or $V_{I} > V_{CC} + 0.5V$	±20	mA
I_{OK} Output Clamp Current $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$		±20	mA
Io	Continuous Output Current -0.5V < V _O V _{CC} +0.5V	+/- 25	mA
I _{CC}	Continuous Current Through Vcc	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
T _J Operating Junction Temperature		-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

5. Input Voltage cannot exceed V_{CC} to the extent the Maximum clamp current is exceeded.

Recommended Operating Conditions (Note 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	Supply Voltage		4.5	5.5	V
VI	Input Voltage		0	V _{CC}	V
Vo	Output Voltage		0	V _{CC}	V
Δt/ΔV	Input Transition Rise or Fall Rate	V_{CC} = 4.5V to 5.5V		500	ns/V
T _A	Operating Free-Air Temperature		-40	+125	°C

Note: 6. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

		Test Conditions		T _A = -40°C to +85°C		T _A = -40°C to +125°C		1114
Symbol	Parameter		Vcc	Min	Мах	Min	Мах	Unit
VIH	High-level Input Voltage		4.5V to 5.5V	2.0		2.0		V
VIL	Low-level Input Voltage		4.5V to 5.5V		0.8		0.8	V
High-level Output		I _{OH} = -20μA	4.5V	4.4		4.4		
V _{OH} Voltage	I _{OH} = -4mA	4.5V	3.80		3.70		V	
V _{OL} Low-level Output Voltage	I _{OL} = 20μΑ	4.5V		0.1		0.1	V	
	I _{OL} = 4mA	4.5V		0.33		0.4		
lı –	Input Current	V _I =GND to 6.0V	6.0V		± 1		± 1	μA
I _{CC}	Supply Current	$V_{I} = GND \text{ or } V_{CC}, I_{O} = 0$	6.0V		20		40	μA
ΔI _{CC}	Additional Supply Current	One input at V_{CC} –2.1V Other pins at V_{CC} or GND	4.5V to 5.5V		675		735	μΑ



Switching Characteristics

Sympol	Demonster	Test	V	٦	Γ _A = +25°C	•	-40°C to +85°C	-40°C to +125°C	11
Symbol	Parameter	Conditions	V _{cc}	Min	Тур	Max	Мах	Max	Unit
t _{PD}	Propagation Delay A_N to Y_N	Figure 1 C _L = 50pF	4.5V	_	11	24	30	36	ns
tı	Transition Time	Figure 1 C _L = 50pF	4.5V	_	7	15	19	22	ns

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

Parameter		Test Conditions	V _{CC} = 5.5 V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	28	pF
CI	Input Capacitance	$V_I = V_{CC} - or GND$	4	pF

Parameter Measurement Information



Propagation Delay Times Inverting and Non Inverting Outputs

- Notes: A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate \leq 1 MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as t_{PD} .

Figure 1 Load Circuit and Voltage Waveforms



Ordering Information



Marking Information

(1) SO-14, TSSOP-14





Package Outline Dimensions (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14					
Dim	Min	Max				
Α	1.47	1.73				
A1	0.10	0.25				
A2	1.45	Тур				
В	0.33	0.51				
D	8.53	8.74				
Е	3.80	3.99				
е	1.27	Тур				
Н	5.80	6.20				
L	0.38	1.27				
θ	0°	8°				
All Di	mension	s in mm				

Package Type: TSSOP-14



	TSSOP-14					
Dim	Min	Max				
a1	7° (4X)				
a2	0°	8°				
Α	4.9	5.10				
в	4.30	4.50				
C		1.2				
D	0.8	1.05				
F	1.00	Тур				
F1	0.45	0.75				
G	0.65	Тур				
Κ	0.19	0.30				
L	L 6.40 Typ					
All Dir	nension	s in mm				



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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